

IN THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1. - 3. (cancelled)

4. - 6. (Cancelled)

7. (cancelled)

8. (previously amended) A voltage tolerant circuit for protecting an input buffer, comprising:

an n-channel pass gate transistor having a first terminal coupled to a pad I/O, a second terminal coupled to an input of an input buffer, and a gate coupled to an internal ring voltage (Ring V<sub>DD</sub>);

a p-supply p-channel transistor having a gate coupled to the pad I/O, a first terminal coupled to Ring V<sub>DD</sub>, and a second terminal coupled to a p-supply of the input buffer, wherein the p-supply is a voltage supplied to a p-channel transistor in the input buffer; and

a p-channel transistor having a first terminal coupled the pad I/O, a gate coupled to Ring V<sub>DD</sub>, and a second terminal coupled to a first terminal of an n-channel transistor.

9. (Cancelled)

10. (currently amended) A voltage tolerant circuit as recited in claim 8, wherein the n-channel transistor further includes a gate coupled to Ring V<sub>DD</sub> and a second terminal coupled to the p-supply of the input buffer.

11. (original) A voltage tolerant circuit as recited in claim 8, wherein the input buffer is an inverter.

12. (original) A voltage tolerant circuit as recited in claim 11, wherein the inverter includes a p-channel transistor having a first terminal coupled to the p-supply of the input buffer, a gate coupled to the input of the input buffer, and a second terminal coupled to an output of the input buffer.

13. (original) A voltage tolerant circuit as recited in claim 12, wherein the inverter further includes an n-channel transistor having a first terminal coupled to the output of the input buffer, a gate coupled to the input of the input buffer, and a second terminal coupled to ground.

14. (original) A voltage tolerant circuit as recited in claim 8, wherein the voltage tolerant I/O is implemented utilizing an I/O generator.

15. (currently amended) A voltage tolerant architecture, comprising:

an input buffer having an input, an output, and a p-supply, wherein the p-supply is a voltage supplied to a p-channel transistor in the input buffer; and

a voltage tolerant I/O circuit having an n-channel pass gate transistor having a first terminal coupled to a pad I/O and a second terminal coupled to an input of an input buffer, and a p-supply p-channel transistor having a gate coupled to the pad I/O, a first terminal coupled to Ring  $V_{DD}$ , and a second terminal coupled to the p-supply of the input buffer, the voltage tolerant I/O circuit further comprising a [[a]] p-channel transistor having a first terminal coupled to the pad I/O, a gate coupled to Ring  $V_{DD}$ , and a second terminal coupled to a first terminal of an n-channel transistor.

16. (Cancelled)

17. (previously amended) A voltage tolerant architecture as recited in claim 15, wherein the n-channel transistor further includes a gate coupled to Ring  $V_{DD}$  and a second terminal coupled to the p-supply of the input buffer.

18. (original) A voltage tolerant architecture as recited in claim 15, wherein the input buffer is an inverter.

19. (original) A voltage tolerant architecture as recited in claim 18, wherein the inverter includes a p-channel transistor having a first terminal coupled to the p-supply of the input buffer, a gate coupled to the input of the input buffer, and a second terminal coupled to an output of the input buffer.

20. (previously amended) A voltage tolerant architecture as recited in claim 15, wherein the voltage tolerant I/O circuit is implemented utilizing an I/O generator.